

Features

- 400 mA pulsed output current
- DC to 30 MHz bandwidth
- 200 V/ μ s slew rate
- Low harmonic distortion
- High input impedance—400 k Ω
- Low output impedance—6 Ω
- High power efficiency
- Operation from ± 5 V to ± 20 V
- Output voltage swing approaches supply voltage
- MIL-STD-883 devices manufactured in U.S.A.

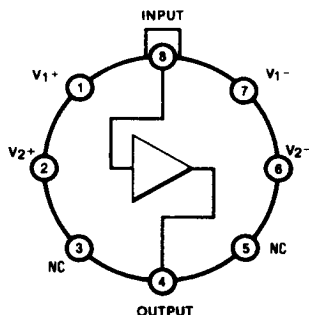
Applications

- Line driver
- 30 MHz buffer
- High-speed D/A conversion
- Instrumentation buffer
- Precision current source

Ordering Information

Part No.	Temp. Range	Pkg.	Outline #
ELH0002H/883B	-55°C to +125°C	TO-5	MDP0001

7801301XX is the DESC version of this device.



Top View

Case is electrically isolated.

General Description

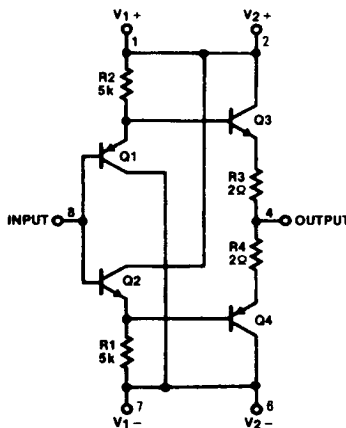
The ELH0002 is a general purpose hybrid current amplifier buffer that is built on a single substrate.

The ELH0002 is ideal for current buffering operational amplifiers without changing the characteristics of the Op Amp. The ELH0002 uses a completely symmetrical circuit to provide a low output impedance when both sourcing and sinking current. This means the output will drive coaxial cables and other capacitive loads with equivalent rise and fall times.

The ELH0002 is specified for operation over the -55°C to +125°C military temperature range.

Elantec facilities comply with MIL-I-45208A and are MIL-STD-1772 certified. Elantec's Military devices comply with MIL-STD-883B Revision C and are manufactured in our rigidly controlled, ultra-clean facilities in Milpitas, California. For additional information on Elantec's Quality and Reliability Assurance Policy and procedures request brochure QRA-1.

Equivalent Schematic



0002-2

ELH0002H/883/7801301XX

Current Amplifier

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

V_S	Supply Voltage	$\pm 22\text{V}$	T_A	Operating Temperature Range	
V_{IN}	Input Voltage	$\pm 22\text{V}$		ELH0002	-55°C to $+125^\circ\text{C}$
P_D	Power Dissipation Ambient	600 mW		Steady State Current	$\pm 100\text{mA}$
T_{ST}	Storage Temperature	-65°C to $+150^\circ\text{C}$		Pulsed Output Current (50 ms On/1 second Off)	$\pm 400\text{mA}$

Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at $T_A = 25^\circ\text{C}$ and QA sample tested at $T_A = 25^\circ\text{C}$, T_{MAX} and T_{MIN} per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at $T_A = 25^\circ\text{C}$ for information purposes only.

DC Electrical Characteristics $V_S = \pm 12\text{V}$, $T_{MIN} \leq T_A \leq T_{MAX}$

Parameter	Description	Test Conditions	ELH0002				Units
			Min	Typ	Max	Test Level	
V_{OS}	Output Offset Voltage	$R_S = 300\Omega$, $R_L = 1\text{ k}\Omega$		± 10	± 30	I	mV
A_V	Voltage Gain	$R_S = 10\text{ k}\Omega$, $R_L = 1\text{ k}\Omega$, $V_{IN} = \pm 10\text{ V}_{dc}$	0.95	0.97		I	V/V
R_{IN}	Input Impedance	$R_S = 200\text{ k}\Omega$, $V_{IN} = \pm 1\text{ V}_{dc}$, $R_L = 1\text{ k}\Omega$	180	400		I	$\text{k}\Omega$
R_{OUT}	Output Impedance	$R_S = 50\Omega$, $V_{IN} = \pm 1\text{ V}_{dc}$, $R_S = 10\text{ k}\Omega$		6_Ω			
V_O	Output Voltage Swing	$V_{IN} = \pm 12\text{V}$, $R_L = 1\text{ K}\Omega$	± 10	± 11		I	V
		$V_S = \pm 15\text{V}$, $V_{IN} = \pm 12\text{V}$, $R_S = 50\Omega$, $R_L = 100\Omega$, $T_A = 25^\circ\text{C}$	± 10			I	V
I_B	Input Current	$R_S = 10\text{ k}\Omega$, $R_L = 1\text{ k}\Omega$		± 6	± 10	I	μA
I_{S+}	Positive Supply Current	$R_S = 10\text{ k}\Omega$, $R_L = 1\text{ k}\Omega$		6	10	I	mA
I_{S-}	Negative Supply Current	$R_S = 10\text{ k}\Omega$, $R_L = 1\text{ k}\Omega$		-6	-10	I	mA

Note 1: Elantec's ELH0002H/200 is tested to the ELH0002 DC limits at -25°C , $+25^\circ\text{C}$ and $+125^\circ\text{C}$, and the AC limits at 25°C . In addition, the parts are also tested to the DC limits for V_{OS} , A_{VOL} with $R_L = 1\text{ k}\Omega$, I_{IN} , I_{S+} and I_{S-} at 200°C .

ELH0002H/883/7801301XX

Current Amplifier

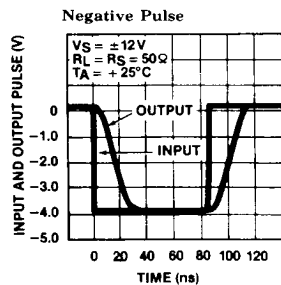
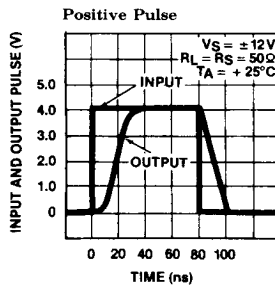
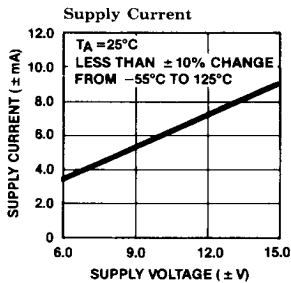
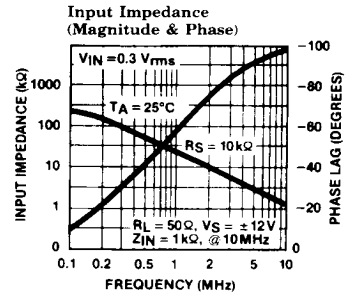
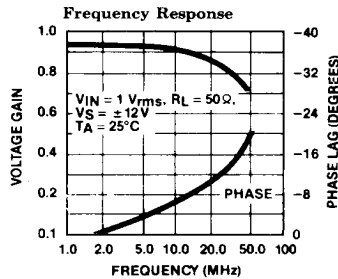
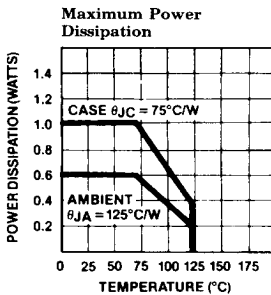
ELH0002H/883/7801301XX

2

AC Electrical Characteristics $V_S = \pm 12V, T_A = 25^\circ C$

Parameter	Description	Test Conditions	ELH0002				Units
			Min	Typ	Max	Test Level	
A_V	Voltage Gain	$R_S = 10\text{ k}\Omega, R_L = 1\text{ k}\Omega$ $V_{IN} = 3\text{ V}_{P-P}, f = 1\text{ kHz}$	0.95	0.97		I	V/V
A_I	Current Gain	$V_{IN} = 1\text{ V}_{RMS}, f = 1\text{ kHz}$		40			A/mA
R_{IN}	Input Impedance	$R_S = 200\text{ k}\Omega, V_{IN} = 1\text{ V}_{RMS}$ $R_L = 1\text{ k}\Omega, f = 1\text{ kHz}$	180	400		I	$\text{k}\Omega$
R_{OUT}	Output Impedance	$R_L = 50\Omega, V_{IN} = 1\text{ V}_{RMS}$ $R_S = 10\text{ k}\Omega, f = 1\text{ kHz}$		6	10	I	Ω
HD	Harmonic Distortion	$V_{IN} = 5\text{ V}_{RMS}, f = 1\text{ kHz}$		0.1		V	%
t_r	Rise Time	$R_L = 50\Omega, \Delta V_{IN} = 100\text{ mV}$		7	12	III	ns

Typical Performance Curves

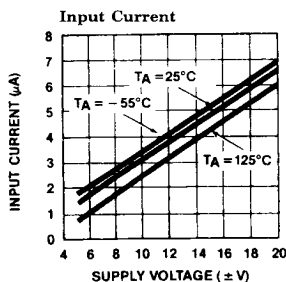


0002-3

ELH0002H/883/7801301XX

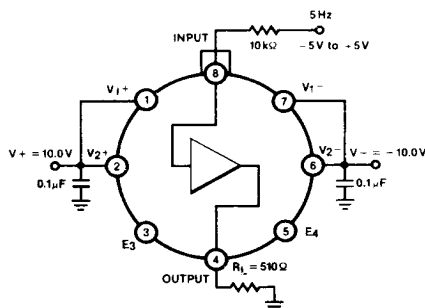
Current Amplifier

Typical Performance Curves — Contd.



0002-4

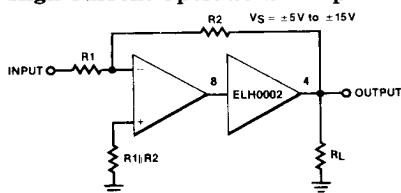
Burn-In Circuit



0002-5

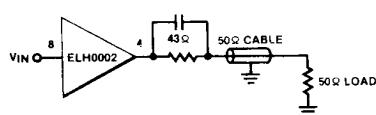
Typical Applications

High Current Operational Amplifier



0002-6

Line Driver



Select capacitor to adjust time response of pulse.

0002-7

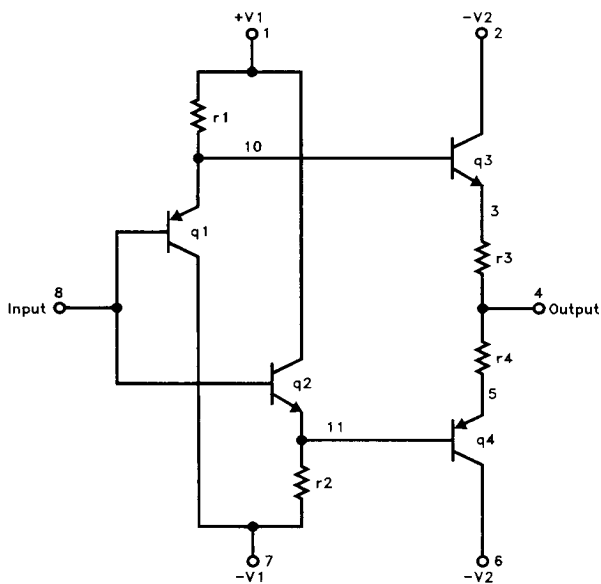
2

2-7

ELH0002H/883/7801301XX

Current Amplifier

ELH0002 Macromodel — Contd.



0002-9